Product Preview

SWITCHMODE™ Soft Recovery Power Rectifier

D²PAK-SL Straight Lead

Designed for use as free wheeling diodes in variable speed motor control applications and other average frequency switching power supplies. These state-of-the-art devices have the following features:

- Soft Recovery with Guaranteed Low Reverse Recovery Charge (Q_{RR}) and Peak Reverse Recovery Current (I_{RRM})
- 150°C Operating Junction Temperature
- Epoxy meets UL94, V_O @ 1/8"
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction

Mechanical Characteristics:

- · Case: Molded Epoxy
- Weight: 1.9 Grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Shipped in 50 Units per Plastic Tube
- Marking: MSRB860



ON Semiconductor®

http://onsemi.com

SOFT RECOVERY
POWER RECTIFIER
8.0 AMPERES, 600 VOLTS



CASE 418C-01, Style 2

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
Average Rectified Forward Current (At Rated V _R , T _C = 125°C)	Io	8.0	Α
Peak Repetitive Forward Current (At Rated V _R , Square Wave, 20 kHz, T _C = 125°C)	I _{FRM}	16	Α
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions, halfwave, single phase, 60 Hz)	I _{FSM}	100	Α
Storage / Operating Case Temperature	T _{stg} , T _C	– 65 to 150	°C
Operating Junction Temperature	TJ	- 65 to 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance — Junction-to-Case	$R_{ heta$ JC	1.6	°C/W
Thermal Resistance — Junction-to-Ambient	$R_{ heta JA}$	72.8	

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (1) (I _F = 8.0 A)	V _F	T _J = 25°C	T _J = 150°C	V
Typical		1.7 1.4	1.3 1.1	
Maximum Instantaneous Reverse Current (V _R = 600 V)	I _R	T _J = 25°C	T _J = 150°C	μΑ
Typical	1	10 2.0	1000 <i>80</i>	
Maximum Reverse Recovery Time (2) (V_R = 400 V, I_F = 8.0 A, di/dt = 200 A/ μ s)	t _{rr}	T _J = 25°C	T _J = 125°C	ns
Typical	, UIC	120 <i>95</i>	190 <i>125</i>	
Typical Recovery Softness Factor (V _R = 400 V, I _F = 8.0 A, di/dt = 200 A/μs)	s = tb/ta	2.5	3.0	
Typical Peak Reverse Recovery Current (V _R = 400 V, I _F = 8.0 A, di/dt = 200 A/μs)	I _{RRM}	5.8	8.3	Α
Typical Reverse Recovery Charge (V _R = 400 V, I _F = 8.0 A, di/dt = 200 A/μs)	Q_{RR}	350	700	nC
Typical Peak Reverse Recovery Current (V _R = 400 V, I _F = 8.0 A, di/dt = 200 A/μs) Typical Reverse Recovery Charge (V _R = 400 V, I _F = 8.0 A, di/dt = 200 A/μs) (1) Pulse Test: Pulse Width ≤[380 μs, Duty Cycle ≤ 2% (2) T _{RR} measured projecting from 25% of I _{RRM} to zero current Switchmode is a trademark of Motorola, Inc.				

⁽¹⁾ Pulse Test: Pulse Width ≤[380 μs, Duty Cycle ≤ 2%

⁽²⁾ T_{RR} measured projecting from 25% of I_{RRM} to zero current

TYPICAL ELECTRICAL CHARACTERISTICS

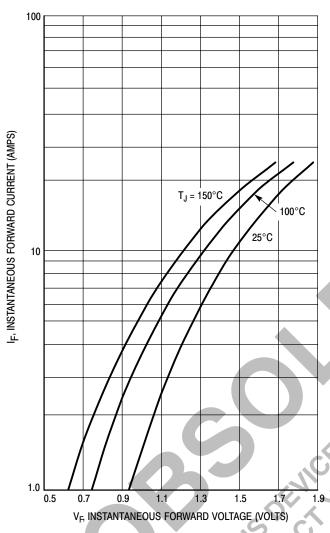


Figure 1. Typical Forward Voltage

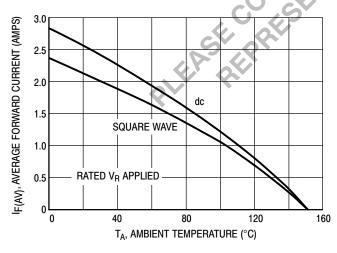


Figure 4. Current Derating, Ambient

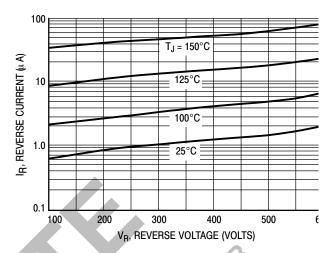


Figure 2. Typical Reverse Current

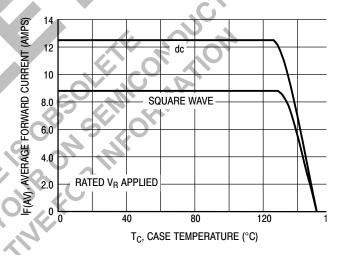


Figure 3. Current Derating, Case

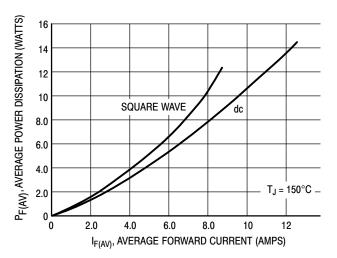
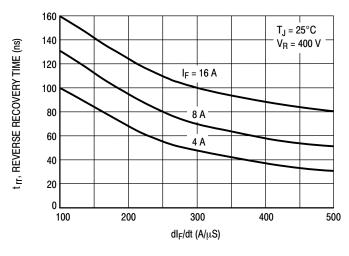


Figure 5. Power Dissipation

TYPICAL ELECTRICAL CHARACTERISTICS



250

T_J = 125°C - V_R = 400 V

150

1_F = 16 A

8 A

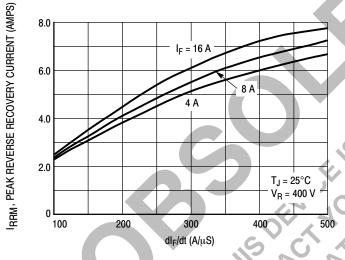
4 A

4 A

dl_F/dt (A/μS)

Figure 6. Typical Reverse Recovery Time

Figure 7. Typical Reverse Recovery Time



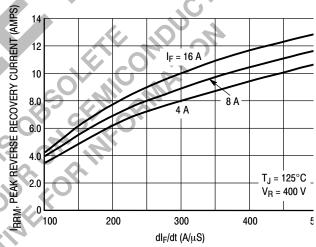
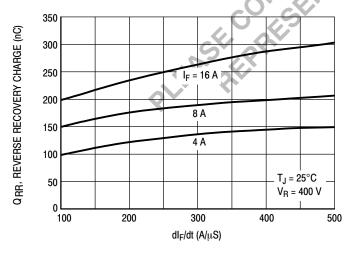


Figure 8. Typical Peak Reverse Recovery Current

Figure 9. Typical Peak Reverse Recovery Current



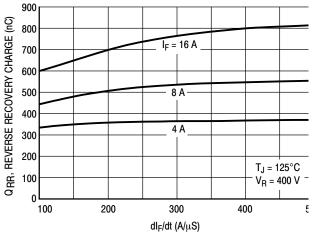
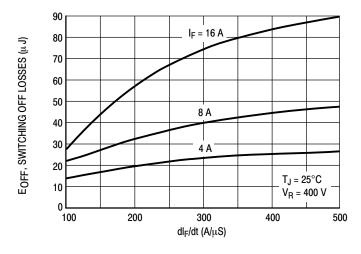


Figure 10. Typical Reverse Recovery Charge

Figure 11. Typical Reverse Recovery Charge



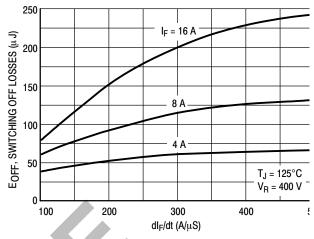
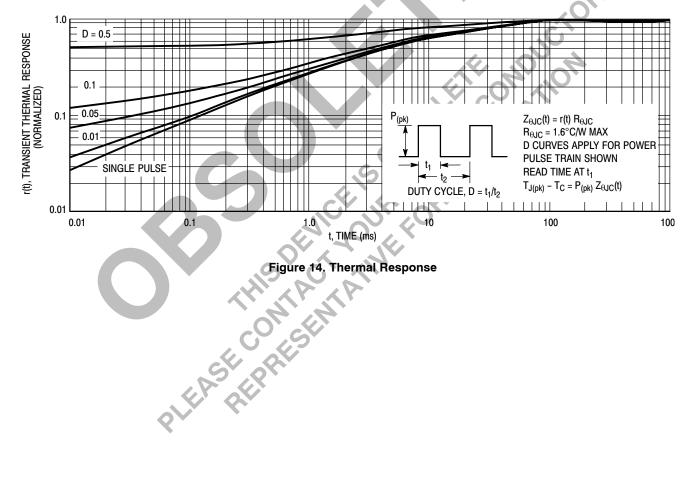


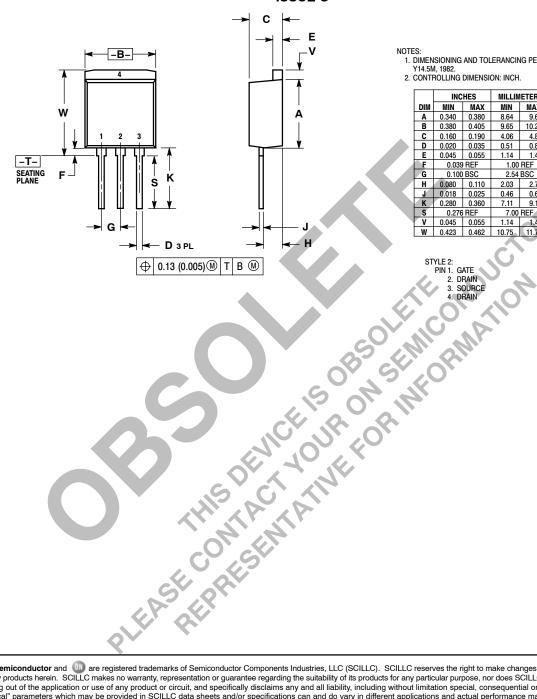
Figure 12. Typical Switching Off Losses

Figure 13. Typical Switching Off Losses



PACKAGE DIMENSIONS

CASE 418C-01 ISSUE O



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.

2.	CON.	TROL	LING	DIMEN	ISION:	INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.340	0.380	8.64	9.65	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.83	
D	0.020	0.035	0.51	0.89	
Е	0.045	0.055	1.14	1.40	
F	0.039	REF	1.00 REF		
G	0.100	BSC	2.54 BSC		
н	0.080	0.110	2.03	2.79	
J	0.018	0.025	0.46	0.64	
K	0.280	0.360	7.11	9.14	
S	0.276 REF		7.00 REF		
٧	0.045	0.055	1.14	1.40	
W	0.423	0.462	10.75	11.75	

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